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Dual Channel Sensorless Motor Control IC for Appliances

Features

- **MCE™ (Motion Control Engine) - Hardware based computation engine for high efficiency sinusoidal sensorless control of permanent magnet AC motor**
- **Integrated Power Factor Correction control**
- **Supports both interior and surface permanent magnet motors**
- **Built-in hardware peripheral for single shunt current feedback reconstruction**
- **No external current or voltage sensing operational amplifier required**
- **Dual channel three/two-phase Space Vector PWM**
- **Three-channel analog output (PWM)**
- **Embedded 8-bit high speed microcontroller (8051) for flexible I/O and man-machine control**
- **JTAG programming port for emulation/debugger**
- **Two serial communication interface (UART)**
- **I²C/SPI serial interface**
- **Watchdog timer with independent analog clock**
- **Three general purpose timers/counters**
- **Two special timers: periodic timer, capture timer**
- **Internal 'One-Time Programmable' (OTP) memory and internal RAM for final production usage**
- **Pin compatible with IRMCF312 RAM version**
- **1.8V/3.3V CMOS**

Product Summary

Maximum crystal frequency	60 MHz
Maximum internal clock (SYSCLK) frequency	128 MHz
Maximum 8051 clock frequency	33 MHz
Sensorless control computation time	11 µsec typ
MCE™ computation data range	16 bit signed
8051 OTP Program memory	56K bytes
MCE program and Data RAM	8K bytes
GateKill latency (digital filtered)	2 µsec
PWM carrier frequency counter	16 bits/ SYSCLK
A/D input channels	11
A/D converter resolution	12 bits
A/D converter conversion speed	2 µsec
8051 instruction execution speed	2 SYSCLK
Analog output (PWM) resolution	8 bits
UART baud rate (typ)	57.6K bps
Number of I/O (max)	36
Package (lead-free)	QFP100
Operating temperature	-40°C ~ 85°C

Description

IRMCK312 is a high performance OTP based motion control IC designed primarily for appliance applications. IRMCK312 is designed to achieve low cost and high performance control solutions for advanced inverterized appliance motor control. IRMCK312 contains two computation engines. One is Motion Control Engine (MCE™) for sensorless control of permanent magnet motors; the other is an 8-bit high-speed microcontroller (8051). Both computation engines are integrated into one monolithic chip. The MCE™ contains a collection of control elements such as Proportional plus Integral, Vector rotator, Angle estimator, Multiply/Divide, Low loss SVPWM, Single Shunt IFB. The user can program a motion control algorithm by connecting these control elements using a graphic compiler. Key components of the sensorless control algorithms, such as the Angle Estimator, are provided as complete pre-defined control blocks implemented in hardware. A unique analog/digital circuit and algorithm to fully support single shunt current reconstruction is also provided. The 8051 microcontroller performs 2-cycle instruction execution (16MIPS at 33MHz). The MCE and 8051 microcontroller are connected via dual port RAM to process signal monitoring and command input. An advanced graphic compiler for the MCE™ is seamlessly integrated into the MATLAB/Simulink environment, while third party JTAG based emulator tools are supported for 8051 developments. IRMCK312 comes with a small QFP100 pin lead-free package.

TABLE OF CONTENTS

1	Overview.....	5
2	IRMCK312 Block Diagram and Main Functions.....	6
3	Pinout.....	8
4	Input/Output of IRMCK312.....	9
4.1	8051 Peripheral Interface Group.....	10
4.2	Motion Peripheral Interface Group.....	11
4.3	Analog Interface Group.....	11
4.4	Power Interface Group.....	12
4.5	Test Interface.....	12
5	Application Connections.....	13
6	DC Characteristics.....	14
6.1	Absolute Maximum Ratings.....	14
6.2	System Clock Frequency and Power Consumption.....	14
6.3	Digital I/O DC Characteristics.....	15
6.4	PLL and Oscillator DC Characteristics.....	16
6.5	Analog I/O DC Characteristics.....	16
6.6	Under Voltage Lockout DC Characteristics.....	17
6.7	AREF Characteristics.....	17
7	AC Characteristics.....	18
7.1	PLL AC Characteristics.....	18
7.2	Analog to Digital Converter AC Characteristics.....	19
7.3	Op Amp AC Characteristics.....	19
7.4	SYNC to SVPWM and A/D Conversion AC Timing.....	20
7.5	GATEKILL to SVPWM AC Timing.....	21
7.6	Interrupt AC Timing.....	21
7.7	I ² C AC Timing.....	22
7.8	SPI AC Timing.....	23
7.8.1	SPI Write AC timing.....	23
7.8.2	SPI Read AC Timing.....	24
7.9	UART AC Timing.....	25
7.10	CAPTURE Input AC Timing.....	26
7.11	JTAG AC Timing.....	27
7.12	OTP Programming Timing.....	28
8	I/O Structure.....	29
9	Pin List.....	32
10	Package Dimensions.....	36
11	Part Marking Information.....	37
12	Ordering Information.....	37

TABLE OF FIGURES

Figure 1.	Typical Application Block Diagram Using IRMCK312	5
Figure 2.	IRMCK312 Internal Block Diagram	6
Figure 3.	IRMCK312 Pin Configuration.....	8
Figure 4.	Input/Output of IRMCK312	9
Figure 5.	Application Connection of IRMCK312.....	13
Figure 6.	Clock Frequency vs. Power Consumption.....	14
Figure 7	Crystal oscillator circuit.....	18
Figure 8	Voltage droop of sample and hold.....	19
Figure 9	SYNC to SVPWM and A/D conversion AC Timing.....	20
Figure 10	GATEKILL to SVPWM AC Timing.....	21
Figure 11	Interrupt AC Timing	21
Figure 12	I ² C AC Timing	22
Figure 13	SPI AC Timing	23
Figure 14	SPI Read AC Timing	24
Figure 15	UART AC Timing	25
Figure 16	CAPTURE Input AC Timing.....	26
Figure 17	JTAG AC Timing	27
Figure 18	OTP Programming Timing	28
Figure 19	All digital I/O except motor PWM output	29
Figure 20	RESET, GATEKILL I/O	29
Figure 21	Analog input.....	30
Figure 22	Analog operational amplifier output and AREF I/O structure	30
Figure 23	VPP programming pin I/O structure	30
Figure 24	VSS and AVSS pin structure	31
Figure 25	VDD1 and VDDCAP pin structure.....	31
Figure 26	XTAL0/XTAL1 pins structure	31

TABLE OF TABLES

Table 1.	Absolute Maximum Ratings.....	14
Table 2.	System Clock Frequency.....	14
Table 3.	Digital I/O DC Characteristics	15
Table 4.	PLL DC Characteristics	16
Table 5.	Analog I/O DC Characteristics	16
Table 6.	UVcc DC Characteristics	17
Table 7.	AREF DC Characteristics	17
Table 8.	PLL AC Characteristics	18
Table 9.	A/D Converter AC Characteristics.....	19
Table 10.	Current Sensing OP Amp AC Characteristics.....	19
Table 11.	SYNC AC Characteristics.....	20
Table 12.	GATEKILL to SVPWM AC Timing	21
Table 13.	Interrupt AC Timing.....	21
Table 14.	I ² C AC Timing	22
Table 15.	SPI Write AC Timing.....	23
Table 16.	SPI Read AC Timing.....	24
Table 17.	UART AC Timing.....	25
Table 18.	CAPTURE AC Timing	26
Table 19.	JTAG AC Timing.....	27
Table 20.	OTP Programming Timing.....	28
Table 21.	Pin List	35

1 Overview

IRMCK312 is a new International Rectifier integrated circuit device primarily designed as a one-chip solution for complete inverter controlled appliance dual motor control applications. Unlike a traditional microcontroller or DSP, the IRMCK312 provides a built-in closed loop sensorless control algorithm using the unique Motion Control Engine (MCE™) for permanent magnet motors. The MCE™ consists of a collection of control elements, motion peripherals, a dedicated motion control sequencer and dual port RAM to map internal signal nodes. IRMCK312 also employs a unique single shunt current reconstruction circuit to eliminate additional analog/digital circuitry and enables a direct shunt resistor interface to the IC. The sensorless control is the same for both motors with a single shunt current sensing capability. Motion control programming is achieved using a dedicated graphical compiler integrated into the MATLAB/Simulink™ development environment. Sequencing, user interface, host communication, and upper layer control tasks can be implemented in the 8051 high-speed 8-bit microcontroller. The 8051 microcontroller is equipped with a JTAG port to facilitate emulation and debugging tools. Figure 1 shows a typical application schematic using IRMCK312.

IRMCK312 is intended for volume production purpose and contains 64K bytes of OTP (One Time Programming) ROM, which can be programmed through a JTAG port. For a development purpose use, IRMCF312 contains a 48k byte of RAM in place of program OTP to facilitate an application development work. Both IRMCF312 and IRMCK312 come in the same 100-pin QFP package with identical pin configuration to facilitate PC board layout and transition to mass production

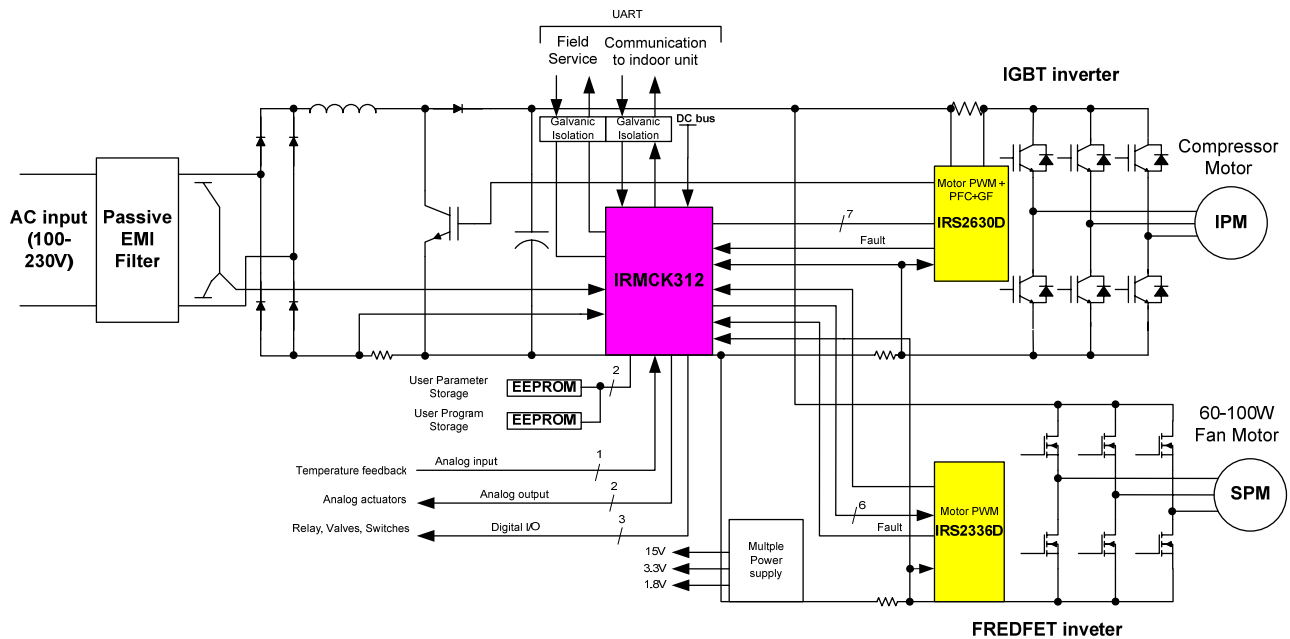


Figure 1. Typical Application Block Diagram Using IRMCK312

2 IRMCK312 Block Diagram and Main Functions

IRMCK312 block diagram is shown in Figure 2.

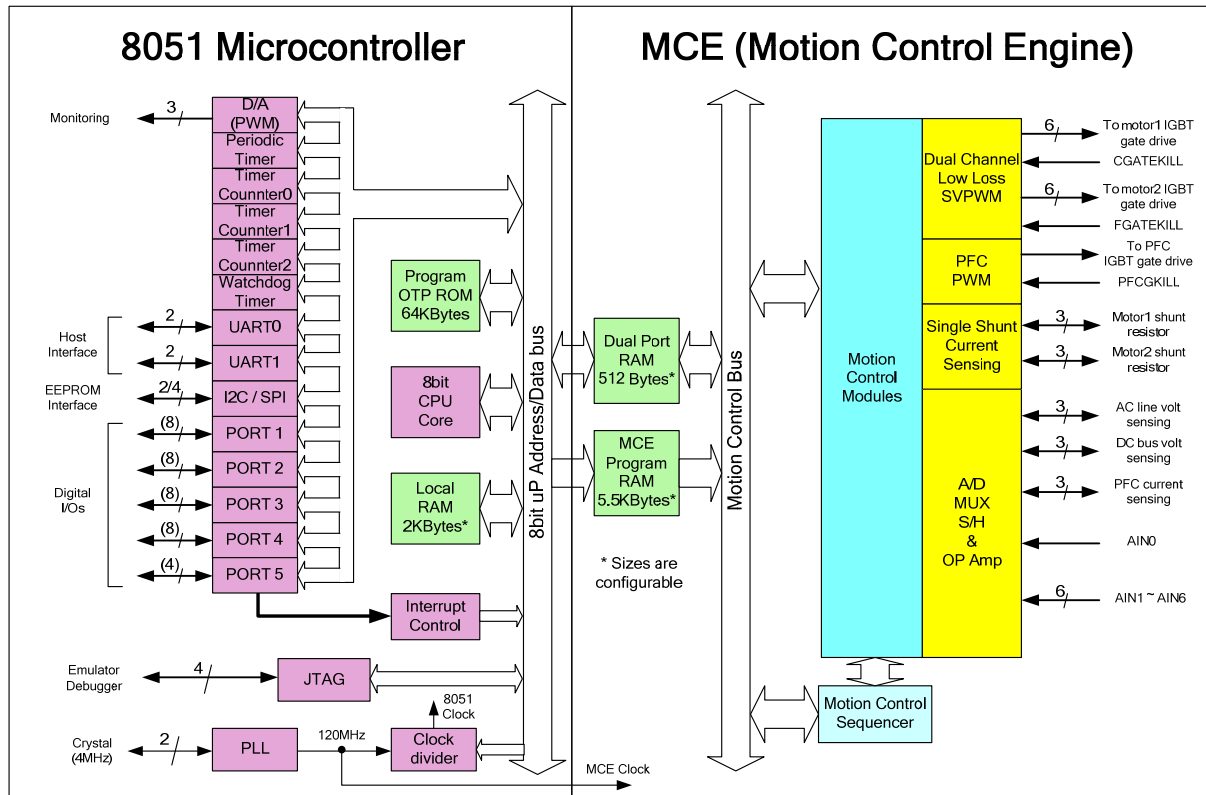


Figure 2. IRMCK312 Internal Block Diagram

IRMCK312 contains the following functions for sensorless AC motor control applications:

- Motion Control Engine (MCE™)
 - Proportional plus Integral block
 - Low pass filter
 - Differentiator and lag (high pass filter)
 - Ramp
 - Limit
 - Angle estimate (sensorless control)
 - Inverse Clark transformation
 - Vector rotator
 - Bit latch
 - Peak detect
 - Transition
 - Multiply-divide (signed and unsigned)
 - Divide (signed and unsigned)

- Adder
 - Subtractor
 - Comparator
 - Counter
 - Accumulator
 - Switch
 - Shift
 - ATAN (arc tangent)
 - Function block (any curve fitting, nonlinear function)
 - 16-bit wide Logic operations (AND, OR, XOR, NOT, NEGATE)
 - MCE™ program and data memory (6K byte). ^{Note 1}
 - MCE™ control sequencer
- 8051 microcontroller
 - Three 16-bit timer/counters
 - 16-bit periodic timer
 - 16-bit analog watchdog timer
 - 16-bit capture timer
 - Up to 36 discrete I/Os
 - Eleven-channel 12-bit A/D
 - Five buffered channels (0 – 1.2V input)
 - Six unbuffered channels (0 – 1.2V input)
 - JTAG port (4 pins)
 - Up to three channels of analog output (8-bit PWM)
 - Two UART
 - I²C/SPI port
 - 64K byte ^{Note 1} program One-Time Programmable memory
 - 2K byte data RAM. ^{Note 2}

Note 1: Total size of OTP memory is 64K byte, however MCE program occupies maximum 8K byte which will be loaded into internal RAM at a powerup/boot process. Therefore only 56K byte OTP memory area is usable for 8051 microcontroller.

Note 2: Total size of RAM is 8K byte including MCE program, MCE data, and 8051 data. Different sizes can be allocated depending on applications.

3 Pinout

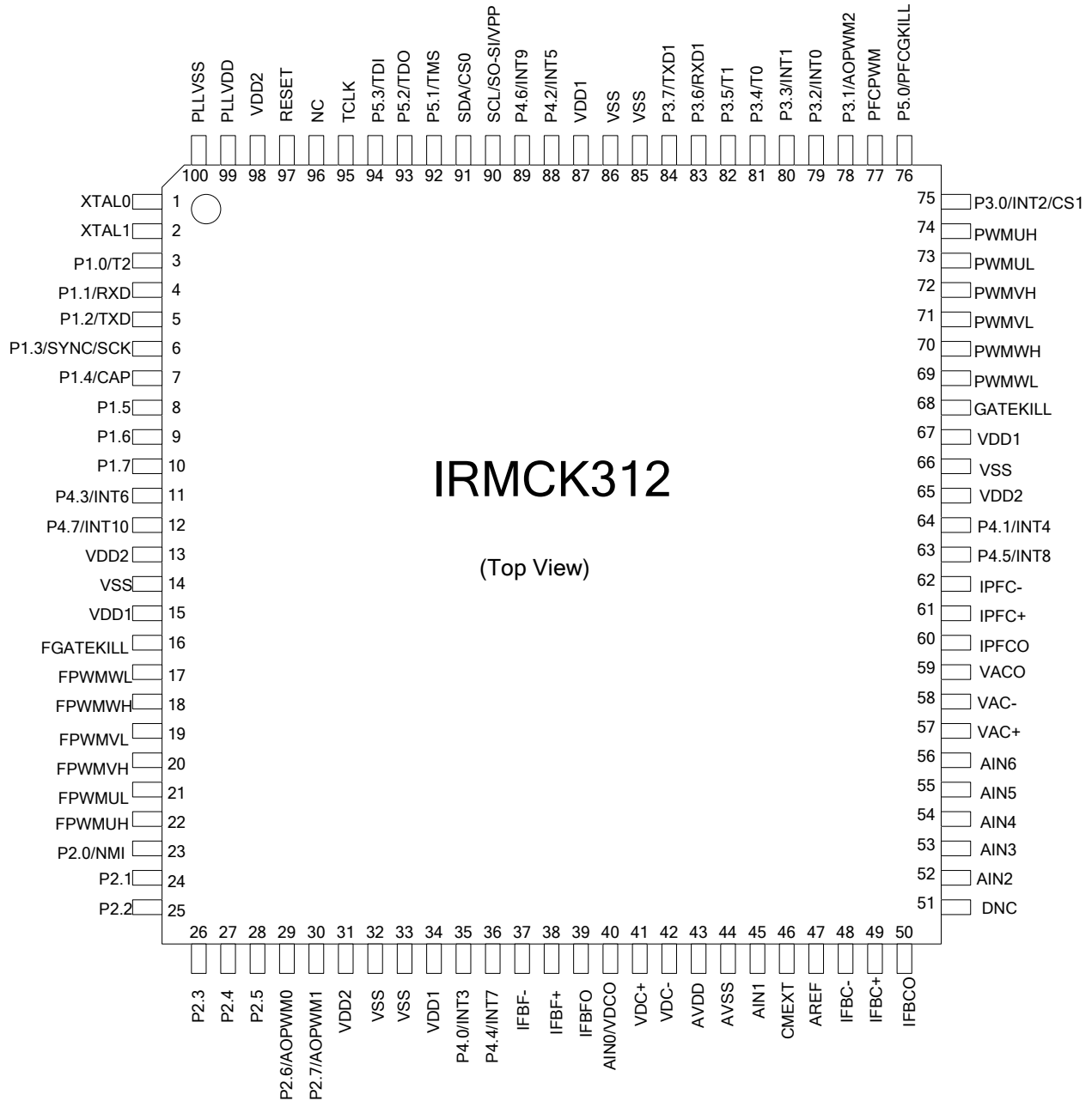


Figure 3. IRMCK312 Pin Configuration

Attention: Pin 51 must be left floating. Do not connect.

4 Input/Output of IRMCK312

All I/O signals of IRMCK312 are shown in Figure 4. All I/O pins are 3.3V logic interface except A/D interface pins.

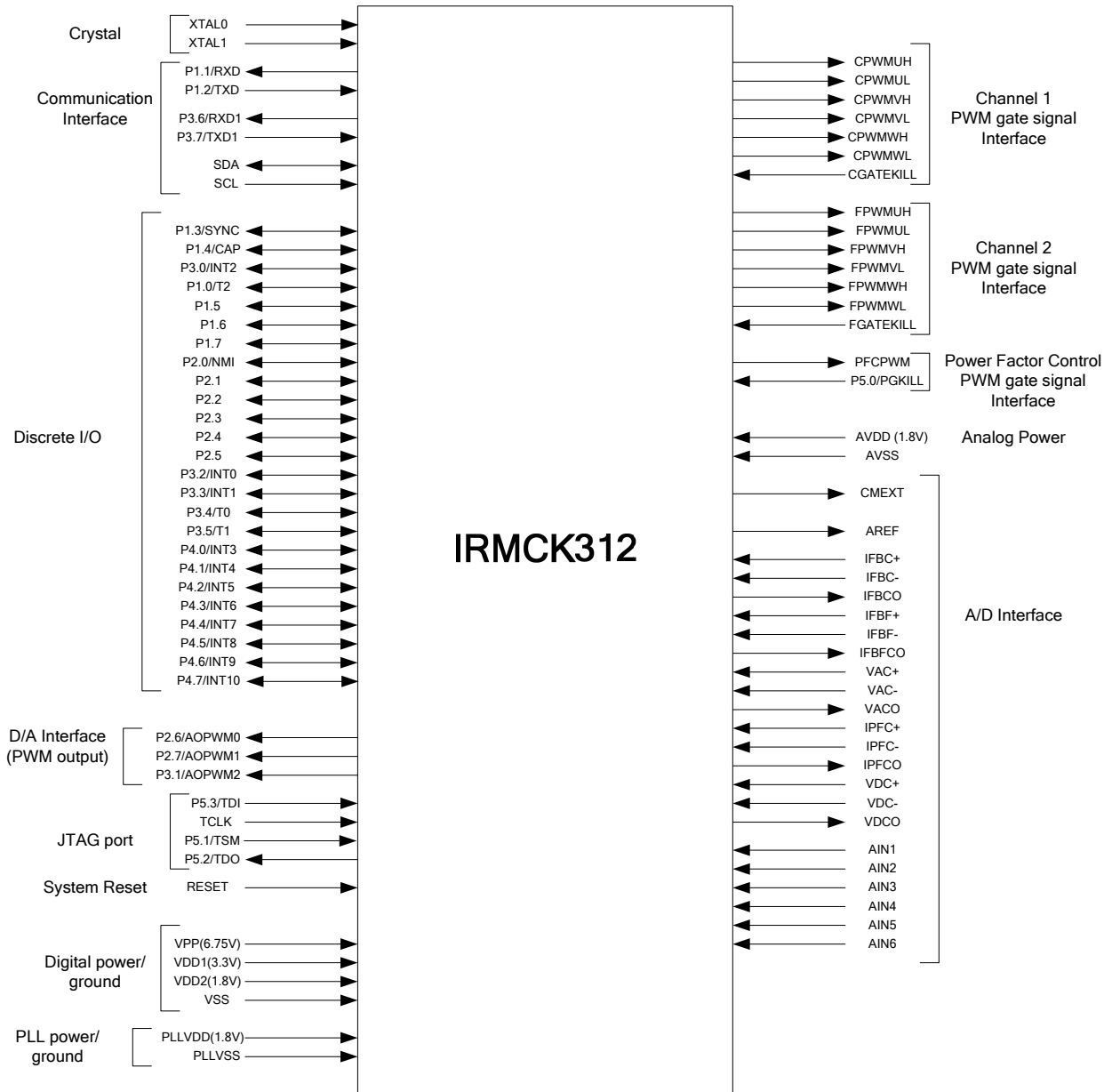


Figure 4. Input/Output of IRMCK312

4.1 8051 Peripheral Interface Group

UART Interface

P1.1/RXD	Input, Receive data to IRMCK312, can be configured as P1.1
P1.2/TXD	Output, Transmit data from IRMCK312, can be configured as P1.2
P3.6/RXD1	Input, 2 nd channel Receive data to IRMCK312, can be configured as P3.6
P3.7/TXD1	Output, 2 nd channel Transmit data from IRMCK312, can be configured as P3.7

Discrete I/O Interface

P1.0/T2	Input/output port 1.0, can be configured as Timer/Counter 2 input
P1.3/SYNC/SCK	Input/output port 1.3, can be configured as SYNC output or SPI clock
P1.4/CAP	Input/output port 1.4, can be configured as Capture Timer input
P1.5	Input/output port 1.5
P1.6	Input/output port 1.6
P1.7	Input/output port 1.7
P2.0/NMI	Input/output port 2.0, can be configured as non-maskable interrupt
P2.1	Input/output port 2.1
P2.2	Input/output port 2.2
P2.3	Input/output port 2.3
P2.4	Input/output port 2.4
P2.5	Input/output port 2.5
P3.0/INT2/CS1	Input/output port 3.0, can be configured as external interrupt 2 or SPI chip select 1
P3.2/INT0	Input/output port 3.2, can be configured as external interrupt 0
P3.3/INT1	Input/output port 3.3, can be configured as external interrupt 1
P3.4/T0	Input/output port 3.4, can be configured as Timer/Counter 0 input
P3.5/T1	Input/output port 3.5, can be configured as Timer/Counter 1 input
P4.0/INT3	Input/output port 4.0, can be configured as external interrupt 3
P4.1/INT4	Input/output port 4.1, can be configured as external interrupt 4
P4.2/INT5	Input/output port 4.2, can be configured as external interrupt 5
P4.3/INT6	Input/output port 4.3, can be configured as external interrupt 6
P4.4/INT7	Input/output port 4.4, can be configured as external interrupt 7
P4.5/INT8	Input/output port 4.5, can be configured as external interrupt 8
P4.6/INT9	Input/output port 4.6, can be configured as external interrupt 9
P4.7/INT10	Input/output port 4.7, can be configured as external interrupt 10
P5.0/PFCGKILL	Input/output port 5.0, can be configured as PFCGKILL
P5.1/TMS	Input/output port 5.1, can be configured as JTAG TMS pin
P5.2/TDO	Input/output port 5.2, can be configured as JTAG TDO pin
P5.3/TDI	Input/output port 5.3, can be configured as JTAG TDI pin

Analog Output Interface

P2.6/AOPWM0	Input/output, can be configured as 8-bit PWM output 0 with programmable carrier frequency
P2.7/AOPWM1	Input/output, can be configured as 8-bit PWM output 1 with programmable carrier frequency
P3.1/AOPWM2	Input/output, can be configured as 8-bit PWM output 2 with programmable carrier frequency

Crystal Interface

XTAL0 Input, connected to crystal
 XTAL1 Output, connected to crystal

Reset Interface

RESET Inout, system reset, needs to be pulled up to VDD1 but doesn't require external RC time constant

I²C/SPI Interface

SCL/SO-SI/VP Output, I²C clock output, SPI SO-SI
 SDA/CS0 Input/output, I²C Data line, Chip Select 0 of SPI
 P3.0/INT2/CS1 Input/output port 3.0, can be configured as external interrupt 2 or SPI chip select 1
 P1.3/SYNC/SCK Input/output port 1.3, can be configured as SYNC output or SPI clock

4.2 Motion Peripheral Interface Group

PWM

CPWMUH Output, motor 1 PWM phase U high side gate signal
 CPWMUL Output, motor 1 PWM phase U low side gate signal
 CPWMVH Output, motor 1 PWM phase V high side gate signal
 CPWMVL Output, motor 1 PWM phase V low side gate signal
 CPWMWH Output, motor 1 PWM phase W high side gate signal
 CPWMWL Output, motor 1 PWM phase W low side gate signal
 FPWMUH Output, motor 2 PWM phase U high side gate signal
 FPWMUL Output, motor 2 PWM phase U low side gate signal
 FPWMVH Output, motor 2 PWM phase V high side gate signal
 FPWMVL Output, motor 2 PWM phase V low side gate signal
 FPWMWH Output, motor 2 PWM phase W high side gate signal
 FPWMWL Output, motor 2 PWM phase W low side gate signal
 PFCPWM Output, PFC PWM

Fault

CGATEKILL Input, upon assertion, this negates all six PWM signals for motor 1, programmable logic sense
 P5.0/PFCGKILL Input, upon assertion, this negates PFCPWM signal, programmable logic sense, can be configured as discrete I/O in which case CGATEKILL negates PFCPWM
 FGATEKILL Input, upon assertion, this negates all six PWM signals for motor 2, programmable logic sense

4.3 Analog Interface Group

AVDD Analog power (1.8V)
 AVSS Analog power return
 AREF Buffered 0.6V output
 CMEXT Unbuffered 0.6V, input to the AREF buffer, capacitor needs to be connected.

IFBC+	Input, Operational amplifier positive input for shunt resistor current sensing of motor 1
IFBC-	Input, Operational amplifier negative input for shunt resistor current sensing of motor 1
IFBCO	Output, Operational amplifier output for shunt resistor current sensing of motor 1
IFBF+	Input, Operational amplifier positive input for shunt resistor current sensing of motor 2
IFBF-	Input, Operational amplifier negative input for shunt resistor current sensing of motor 2
IFBFO	Output, Operational amplifier output for shunt resistor current sensing of motor 2
IPFC+	Input, Operational amplifier positive input for PFC current sensing
IPFC-	Input, Operational amplifier negative input for PFC current sensing
IPFO	Output, Operational amplifier output for PFC current sensing
VAC+	Input, Operational amplifier positive input for PFC AC voltage sensing
VAC-	Input, Operational amplifier negative input for PFC AC voltage sensing
VACO	Output, Operational amplifier output for PFC AC voltage sensing
VDC+	Input, Operational amplifier positive input for DC bus voltage sensing
VDC-	Input, Operational amplifier negative input for DC bus voltage sensing
AIN0/VDCO	Input/Output, Analog input channel 0 or Operational amplifier output for DC bus voltage sensing
AIN1	Input, Analog input channel 1 (0-1.2V), needs to be pulled down to AVSS if unused
AIN2	Input, Analog input channel 2 (0-1.2V), needs to be pulled down to AVSS if unused
AIN3	Input, Analog input channel 3 (0-1.2V), needs to be pulled down to AVSS if unused
AIN4	Input, Analog input channel 4 (0-1.2V), needs to be pulled down to AVSS if unused
AIN5	Input, Analog input channel 5 (0-1.2V), needs to be pulled down to AVSS if unused
AIN6	Input, Analog input channel 6 (0-1.2V), needs to be pulled down to AVSS if unused

4.4 Power Interface Group

VDD1	Digital power for I/O (3.3V)
VDD2	Digital power for core logic (1.8V)
VSS	Digital common
PLLVD	PLL power (1.8V)
PLLVSS	PLL ground return
SCL/SO-SI/VPP	OTP programming supply. Can be left open in OTP read mode (normal)

4.5 Test Interface

P5.3/TDI	Input, JTAG test data input
P5.1/TMS	Input, JTAG test mode select
TCK	Input, JTAG test clock
P5.2/TDO	Output, JTAG test data output

5 Application Connections

Typical application connection is shown in Figure 5. All components necessary to implement a complete sensorless drive control algorithm are shown connected to IRMCK312.

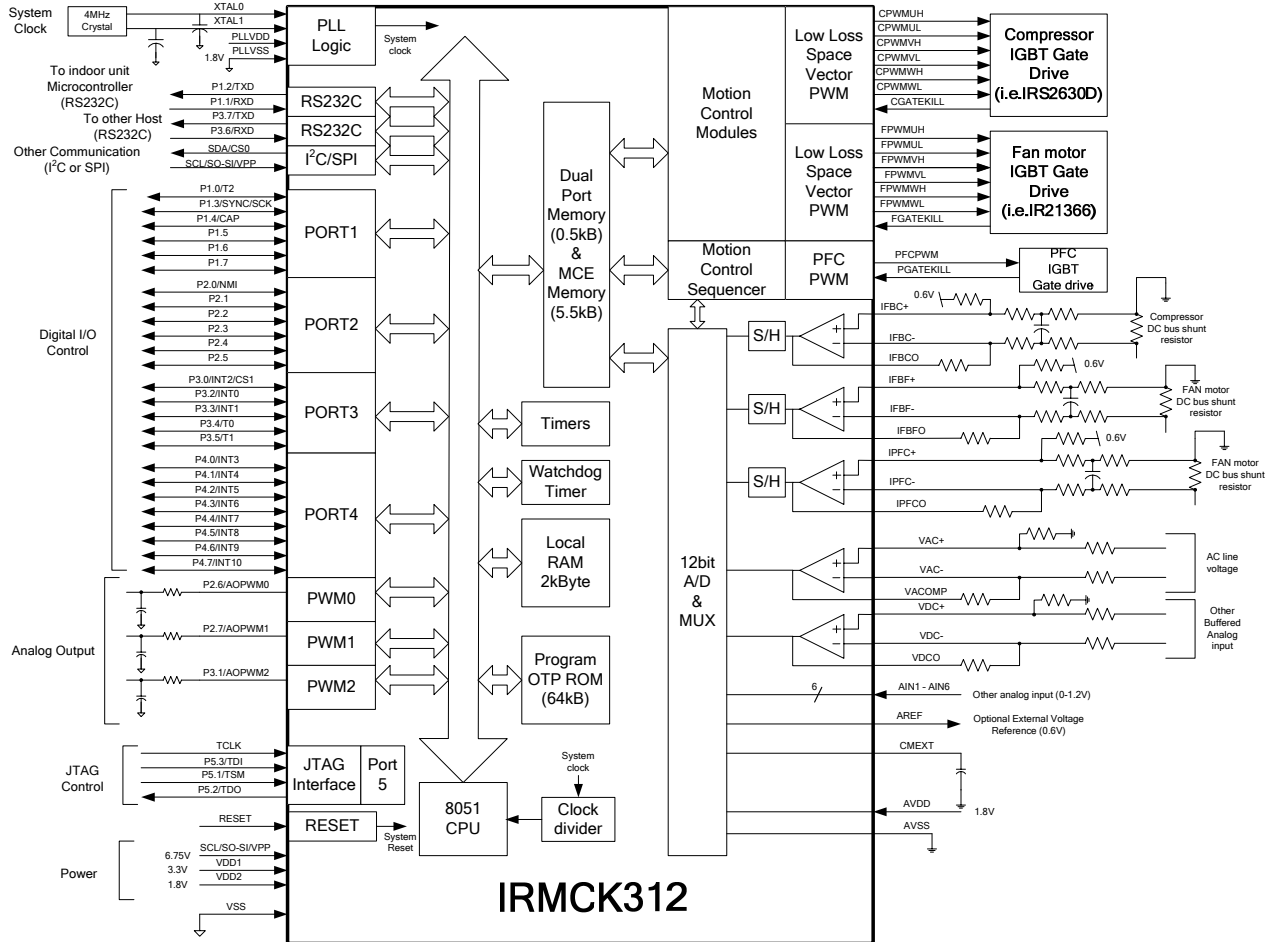


Figure 5. Application Connection of IRMCK312

6 DC Characteristics

6.1 Absolute Maximum Ratings

Symbol	Parameter	Min	Typ	Max	Condition
V _{DD1}	Supply Voltage	-0.3 V	-	3.6 V	Respect to VSS
V _{DD2}	Supply Voltage	-0.3 V	-	1.98 V	Respect to VSS
V _{PP}	OTP Programming Voltage	-0.3V	-	7.0V	Respect to VSS
V _{IA}	Analog Input Voltage	-0.3 V	-	1.98 V	Respect to AVSS
V _{ID}	Digital Input Voltage	-0.3 V	-	3.65 V	Respect to VSS
T _A	Ambient Temperature	-40 °C	-	85 °C	
T _S	Storage Temperature	-65 °C	-	150 °C	

Table 1. Absolute Maximum Ratings

Caution: Stresses beyond those listed in “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only and function of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied.

6.2 System Clock Frequency and Power Consumption

Symbol	Parameter	Min	Typ	Max	Unit
SYSCLK	System Clock	32	-	128	MHz
8051CLK	8051 Clock	-	-	32	MHz

Table 2. System Clock Frequency

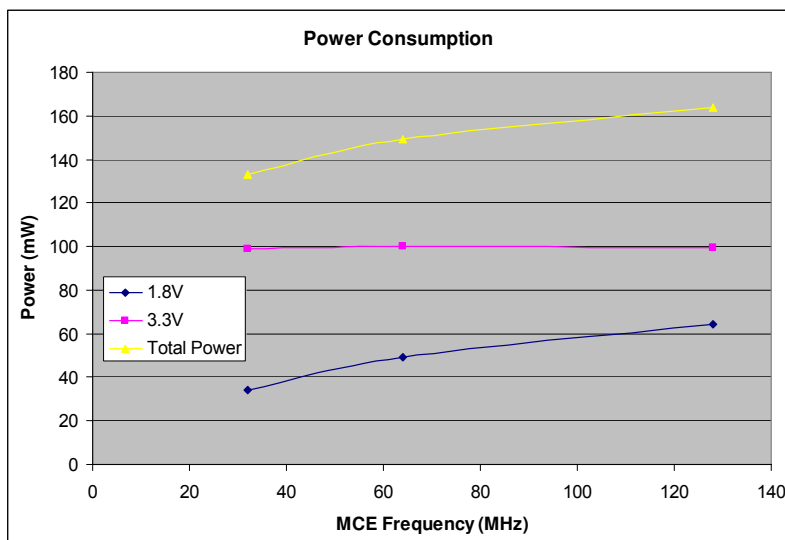


Figure 6. Clock Frequency vs. Power Consumption

6.3 Digital I/O DC Characteristics

Symbol	Parameter	Min	Typ	Max	Condition
V _{DD1}	Supply Voltage	3.0 V	3.3 V	3.6 V	Recommended
V _{DD2}	Supply Voltage	1.62 V	1.8 V	1.98 V	Recommended
V _{PP}	OTP Programming voltage	6.50V	6.75V	7.0V	Recommended
V _{IL}	Input Low Voltage	-0.3 V	-	0.8 V	Recommended
V _{IH}	Input High Voltage	2.0 V		3.6 V	Recommended
C _{IN}	Input capacitance	-	3.6 pF	-	(1)
I _L	Input leakage current		±10 nA	±1 µA	V _O = 3.3 V or 0 V
I _{OL1} ⁽²⁾	Low level output current	8.9 mA	13.2 mA	15.2 mA	V _{OL} = 0.4 V (1)
I _{OH1} ⁽²⁾	High level output current	12.4 mA	24.8 mA	38 mA	V _{OH} = 2.4 V (1)
I _{OL2} ⁽³⁾	Low level output current	17.9 mA	26.3 mA	33.4 mA	V _{OL} = 0.4 V (1)
I _{OH2} ⁽³⁾	High level output current	24.6 mA	49.5 mA	81 mA	V _{OH} = 2.4 V (1)

Table 3. Digital I/O DC Characteristics

Note:

- (1) Data guaranteed by design.
- (2) Applied to SCL/SO-SI, SDA/CS0 pins.
- (3) Applied to P1.0/T2, P1.1/RXD, P1.2/TXD, P1.3/SYNC/SCK, P1.4/CAP, P1.5, P1.6, P1.7, P2.0/NMI, P2.1, P2.2, P2.3, P2.4, P2.5, P2.6/AOPWM0, P2.7/AOPWM1, P3.0/INT2/CS1, P3.1/AOPWM2, P3.2/INT0, P3.3/INT1, P3.4/T0, P3.5/T1, P3.6/RXD1, P3.7/TXD1, P4.0/INT3, P4.1/INT4, P4.2/INT5, P4.3/INT6, P4.4/INT7, P4.5/INT8, P4.6/INT9, P4.7/INT10, P5.0/PFCGKILL, P5.1/TMS, P5.2/TDO, P5.3/TDI, CGATEKILL, FGATEKILL, CPWMUL, CPWMUH, CPWMVL, CPWMVH, CPWMWL, CPWMWH, FPWMUL, FPWMUH, FPWMVL, FPWMVH, FPWMWL, FPWMWH, and PFCPWM pins.

6.4 PLL and Oscillator DC Characteristics

Symbol	Parameter	Min	Typ	Max	Condition
V _{PLLVD}	Supply Voltage	1.62 V	1.8 V	1.92 V	Recommended
V _{IL OSC}	Oscillator Input Low Voltage	V _{PLLSS}	-	0.2* V _{PLLVD}	V _{PLLVD} = 1.8 V (1)
V _{IH OSC}	Oscillator Input High Voltage	0.8* V _{PLLVD}		V _{PLLVD}	V _{PLLVD} = 1.8 V (1)

Table 4. PLL DC Characteristics

Note:

(1) Data guaranteed by design.

6.5 Analog I/O DC Characteristics

- OP amps for current sensing (IFBC+, IFBC-, IFBCO, IFBF+, IFBF-, IFBFO, IPFC+, IPFC-, IPFCO)

C_{CAREF} = 1nF, C_{MEXT} = 100nF. Unless specified, Ta = 25°C.

Symbol	Parameter	Min	Typ	Max	Condition
V _{AVDD}	Supply Voltage	1.71 V	1.8 V	1.89 V	Recommended
V _{OFFSET}	Input Offset Voltage	-	-	26 mV	V _{AVDD} = 1.8 V
V _I	Input Voltage Range	0 V		1.2 V	Recommended
V _{OUTSW}	OP amp output operating range	50 mV (1)	-	1.2 V	V _{AVDD} = 1.8 V
C _{IN}	Input capacitance	-	3.6 pF	-	(1)
R _{FDBK}	OP amp feedback resistor	5 kΩ	-	20 kΩ	Requested between op amp output and negative input
OP _{GAINCL}	Operating Close loop Gain	80 db	-	-	(1)
CMRR	Common Mode Rejection Ratio	-	80 db	-	(1)
I _{SRC}	Op amp output source current	-	1 mA	-	V _{OUT} = 0.6 V (1)
I _{SNK}	Op amp output sink current	-	100 μA	-	V _{OUT} = 0.6 V (1)

Table 5. Analog I/O DC Characteristics

Note: (1) Data guaranteed by design.

6.6 Under Voltage Lockout DC Characteristics

- Based on AVDD (1.8V)

Unless specified, $T_a = 25^\circ\text{C}$.

Symbol	Parameter	Min	Typ	Max	Condition
UV_{CC+}	UVcc positive going Threshold ¹⁾	1.53 V	1.66 V	1.71 V	$V_{DD1} = 3.3\text{ V}$
UV_{CC-}	UVcc negative going Threshold	1.52 V	1.62 V	1.71 V	$V_{DD1} = 3.3\text{ V}$
UV_{CCH}	UVcc Hysteresys	-	40 mV	-	

Table 6. UVcc DC Characteristics

Note:

1) Data guaranteed by design.

6.7 AREF Characteristics

$C_{AREF} = 1\text{nF}$, $C_{MEXT} = 100\text{nF}$. Unless specified, $T_a = 25^\circ\text{C}$.

Symbol	Parameter	Min	Typ	Max	Condition
V_{AREF}	AREF Output Voltage	495 mV	600 mV	700 mV	$V_{AVDD} = 1.8\text{ V}$
ΔV_o	Load regulation ($V_{DC}-0.6$)	-	1 mV	-	⁽¹⁾
PSRR	Power Supply Rejection Ratio	-	75 db	-	⁽¹⁾

Table 7. AREF DC Characteristics

Note:

(1) Data guaranteed by design.

7 AC Characteristics

7.1 PLL AC Characteristics

Symbol	Parameter	Min	Typ	Max	Condition
F _{CLKIN}	Crystal input frequency	3.2 MHz	4 MHz	60 MHz	⁽¹⁾ (see figure below)
F _{PLL}	Internal clock frequency	32 MHz	50 MHz	128 MHz	⁽¹⁾
F _{LWPPW}	Sleep mode output frequency	F _{CLKIN} ÷ 256	-	-	⁽¹⁾
J _S	Short time jitter	-	200 psec	-	⁽¹⁾
D	Duty cycle	-	50 %	-	⁽¹⁾
T _{LOCK}	PLL lock time	-	-	500 μsec	⁽¹⁾

Table 8. PLL AC Characteristics

Note:

(1) Data guaranteed by design.

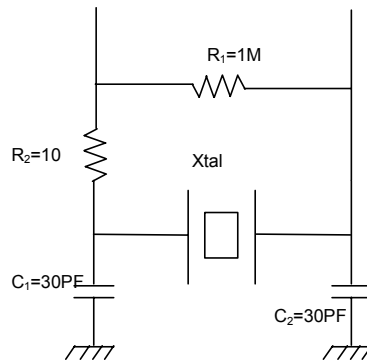


Figure 7 Crystal oscillator circuit

7.2 Analog to Digital Converter AC Characteristics

Unless specified, $T_a = 25^\circ\text{C}$.

Symbol	Parameter	Min	Typ	Max	Condition
T_{CONV}	Conversion time	-	-	2.05 μsec	(1)
T_{HOLD}	Sample/Hold maximum hold time	-	-	10 μsec	Voltage droop \leq 15 LSB (see figure below)

Table 9. A/D Converter AC Characteristics

Note:

(1) Data guaranteed by design.

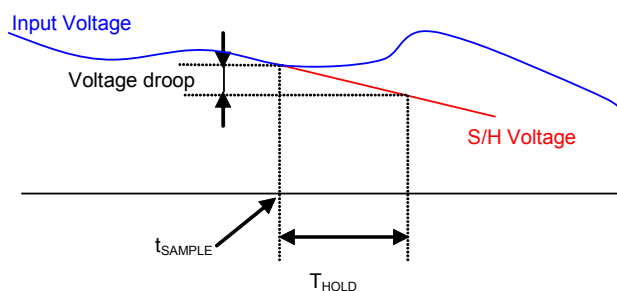


Figure 8 Voltage droop of sample and hold

7.3 Op Amp AC Characteristics

- OP amps for current sensing (IFBC+, IFBC-, IFBCO, IFBF+, IFBF-, IFBFO, IPFC+, IPFC-, IPFCO)

Unless specified, $T_a = 25^\circ\text{C}$.

Symbol	Parameter	Min	Typ	Max	Condition
OP_{SR}	OP amp slew rate	-	10 V/ μsec	-	$V_{\text{AVDD}} = 1.8\text{ V}$, $CL = 33\text{ pF}$ (1)
OP_{IMP}	OP input impedance	-	$10^8\ \Omega$	-	(1)
T_{SET}	Settling time	-	400 ns	-	$V_{\text{AVDD}} = 1.8\text{ V}$, $CL = 33\text{ pF}$ (1)

Table 10. Current Sensing OP Amp AC Characteristics

Note:

(1) Data guaranteed by design.

7.4 SYNC to SVPWM and A/D Conversion AC Timing

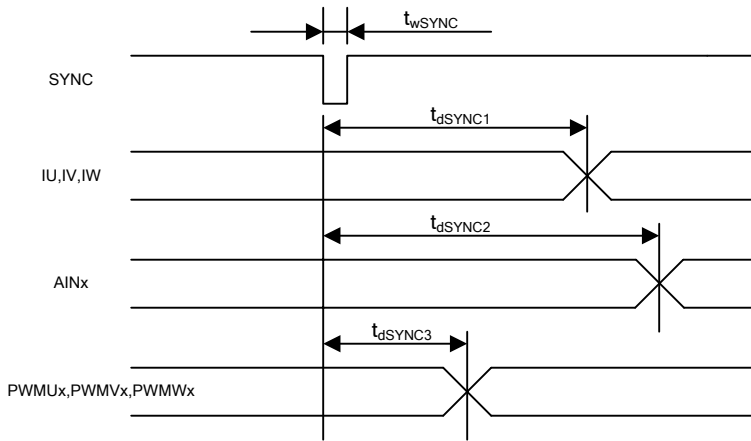


Figure 9 SYNC to SVPWM and A/D conversion AC Timing

Unless specified, $T_a = 25^\circ\text{C}$.

Symbol	Parameter	Min	Typ	Max	Unit
t_{wSYNC}	SYNC pulse width	-	32	-	SYSClk
t_{dSYNC1}	SYNC to current feedback conversion time	-	-	100	SYSClk
t_{dSYNC2}	SYNC to AIN0-6 analog input conversion time	-	-	200	SYSClk ⁽¹⁾
t_{dSYNC3}	SYNC to PWM output delay time	-	-	2	SYSClk

Table 11. SYNC AC Characteristics

Note:

(1) AIN1 through AIN6 channels are converted once every 6 SYNC events

7.5 GATEKILL to SVPWM AC Timing

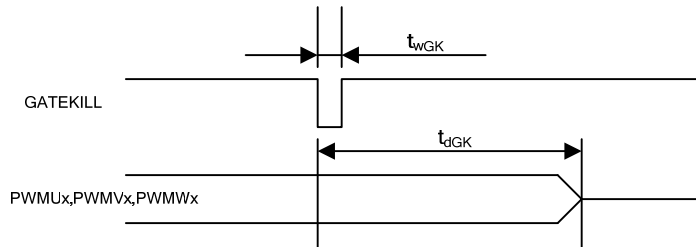


Figure 10 GATEKILL to SVPWM AC Timing

Unless specified, Ta = 25°C.

Symbol	Parameter	Min	Typ	Max	Unit
t_{wGK}	GATEKILL pulse width	32	-	-	SYSClk
t_{dGK}	GATEKILL to PWM output delay	-	-	100	SYSClk

Table 12. GATEKILL to SVPWM AC Timing

7.6 Interrupt AC Timing

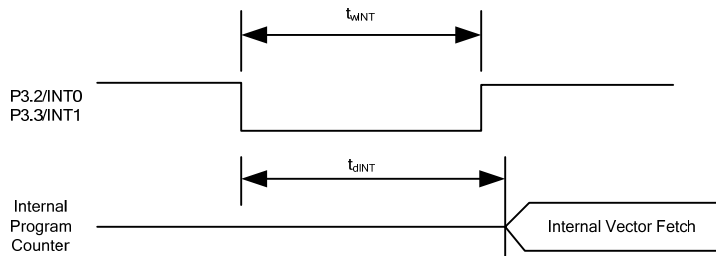


Figure 11 Interrupt AC Timing

Unless specified, Ta = 25°C.

Symbol	Parameter	Min	Typ	Max	Unit
t_{wINT}	INT0, INT1 Interrupt Assertion Time	4	-	-	SYSClk
t_{dINT}	INT0, INT1 latency	-	-	4	SYSClk

Table 13. Interrupt AC Timing

7.7 I²C AC Timing

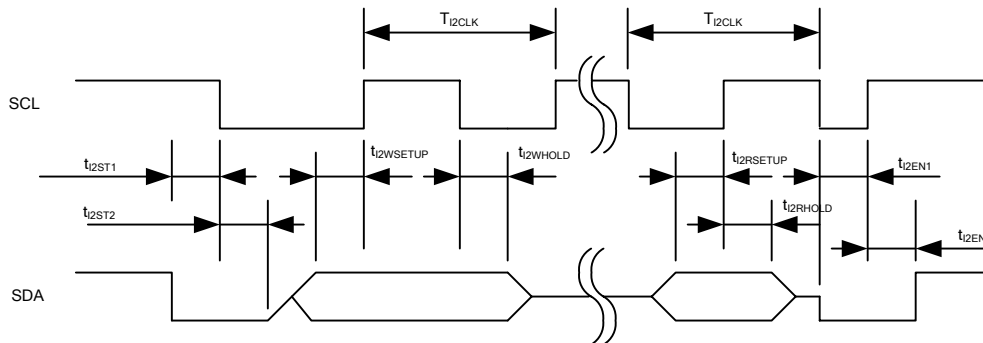


Figure 12 I²C AC Timing

Unless specified, Ta = 25°C.

Symbol	Parameter	Min	Typ	Max	Unit
T _{I2CLK}	I ² C clock period	10	-	8192	SYCLK
t _{I2ST1}	I ² C SDA start time	0.25	-	-	T _{I2CLK}
t _{I2ST2}	I ² C SCL start time	0.25	-	-	T _{I2CLK}
t _{I2WSETUP}	I ² C write setup time	0.25	-	-	T _{I2CLK}
t _{I2WHOLD}	I ² C write hold time	0.25	-	-	T _{I2CLK}
t _{I2RSETUP}	I ² C read setup time	I ² C filter time ⁽¹⁾	-	-	SYCLK
t _{I2RHOLD}	I ² C read hold time	1	-	-	SYCLK

Table 14. I²C AC Timing

Note:

- (1) I²C read setup time is determined by the programmable filter time applied to I²C communication.

7.8 SPI AC Timing

7.8.1 SPI Write AC timing

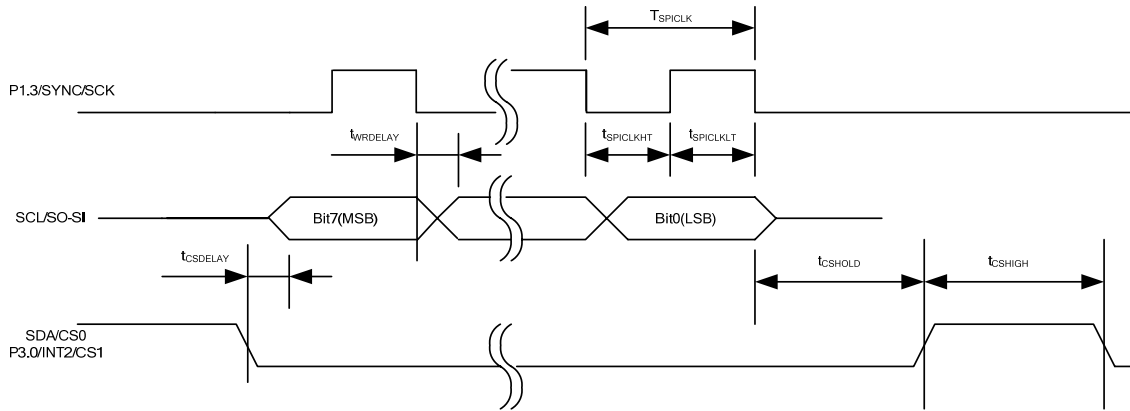


Figure 13 SPI AC Timing

Unless specified, $T_a = 25^\circ\text{C}$.

Symbol	Parameter	Min	Typ	Max	Unit
T_{SPICLK}	SPI clock period	4	-	-	SYSCLK
t_{SPICLKHT}	SPI clock high time	-	1/2	-	T_{SPICLK}
t_{SPICLKLT}	SPI clock low time	-	1/2	-	T_{SPICLK}
t_{CSDELAY}	CS to data delay time	-	-	10	nsec
t_{WRDELAY}	CLK falling edge to data delay time	-	-	10	nsec
t_{CSHIGH}	CS high time between two consecutive byte transfer	1	-	-	T_{SPICLK}
t_{CSHOLD}	CS hold time	-	1	-	T_{SPICLK}

Table 15. SPI Write AC Timing

7.8.2 SPI Read AC Timing

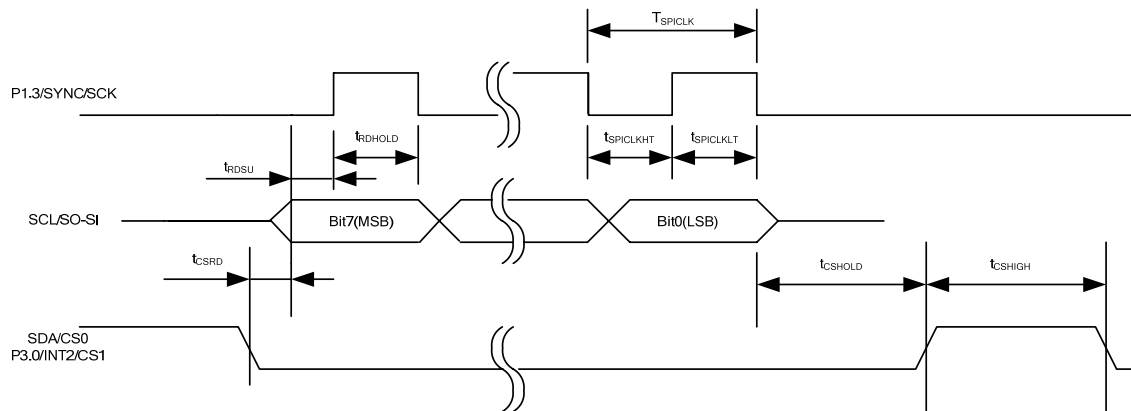


Figure 14 SPI Read AC Timing

Unless specified, $T_a = 25^\circ\text{C}$.

Symbol	Parameter	Min	Typ	Max	Unit
T_{SPICLK}	SPI clock period	4	-	-	SYSCCLK
t_{SPICLKHT}	SPI clock high time	-	1/2	-	T_{SPICLK}
t_{SPICLKLT}	SPI clock low time	-	1/2	-	T_{SPICLK}
t_{CSRd}	CS to data delay time	-	-	10	nsec
t_{RDSU}	SPI read data setup time	10	-	-	nsec
t_{RDHOLD}	SPI read data hold time	10	-	-	nsec
t_{CSHIGH}	CS high time between two consecutive byte transfer	1	-	-	T_{SPICLK}
t_{CSHOLD}	CS hold time	-	1	-	T_{SPICLK}

Table 16. SPI Read AC Timing

7.9 UART AC Timing

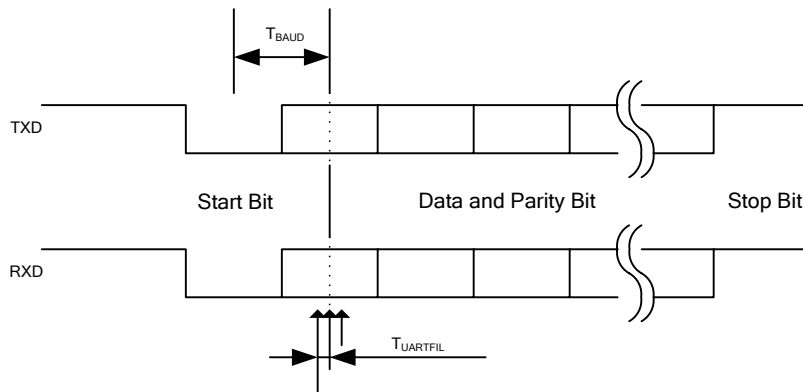


Figure 15 UART AC Timing

Unless specified, $T_a = 25^\circ\text{C}$.

Symbol	Parameter	Min	Typ	Max	Unit
T_{BAUD}	Baud Rate Period	-	57600	-	bit/sec
$T_{UARTFIL}$	UART sampling filter period ⁽¹⁾	-	1/16	-	T_{BAUD}

Table 17. UART AC Timing

Note:

- (1) Each bit including start and stop bit is sampled three times at center of a bit at an interval of $1/16 T_{BAUD}$. If three sampled values do not agree, then UART noise error is generated.